

# CR5AS-12A

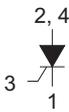
600V - 5A - Thyristor  
Medium Power Use

R07DS0332EJ0300  
Rev.3.00  
Jan 23, 2013

## Features

- $I_{T(AV)}$  : 5 A
- $V_{DRM}$  : 600 V
- $I_{GT}$  : 100  $\mu$ A
- Non-Insulated Type
- Plannar Type

## Outline

RENESAS Package code: PRSS0004ZG-A (Package name: MP-3A)	PRSS0004ZD-D (Package name: DPAK(L)-(3))								
									
									
<table style="border: none;"> <tr> <td style="padding-right: 10px;">1.</td> <td>Cathode</td> </tr> <tr> <td style="padding-right: 10px;">2.</td> <td>Anode</td> </tr> <tr> <td style="padding-right: 10px;">3.</td> <td>Gate</td> </tr> <tr> <td style="padding-right: 10px;">4.</td> <td>Anode</td> </tr> </table>		1.	Cathode	2.	Anode	3.	Gate	4.	Anode
1.	Cathode								
2.	Anode								
3.	Gate								
4.	Anode								

## Applications

Switching mode power supply, regulator for autcycle, protective circuit for TV sets, VCRs, and printers, igniter for autcycle, electric tool, strobe flasher, and other general purpose control applications

## Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak reverse voltage	$V_{RRM}$	600	V
Non-repetitive peak reverse voltage	$V_{RSM}$	720	V
DC reverse voltage	$V_{R(DC)}$	480	V
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	600	V
DC off-state voltage <sup>Note1</sup>	$V_{D(DC)}$	480	V

Notes: 1. With gate to cathode resistance  $R_{GK} = 220 \Omega$ .

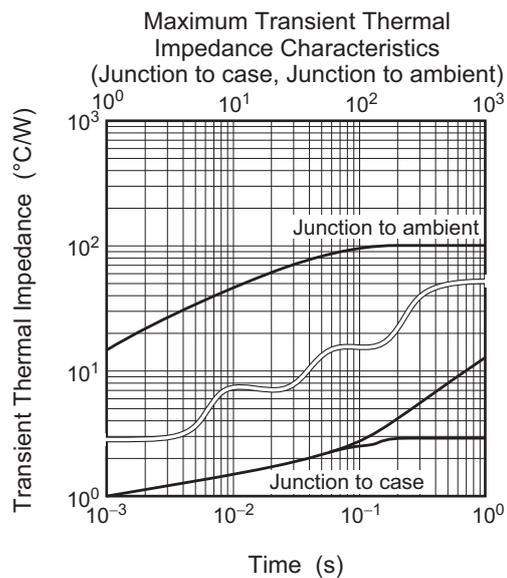
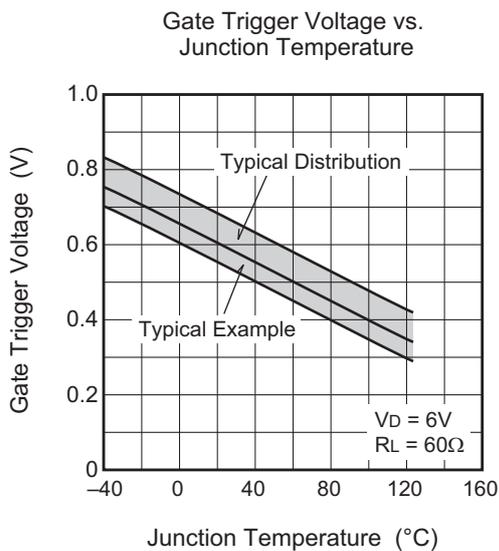
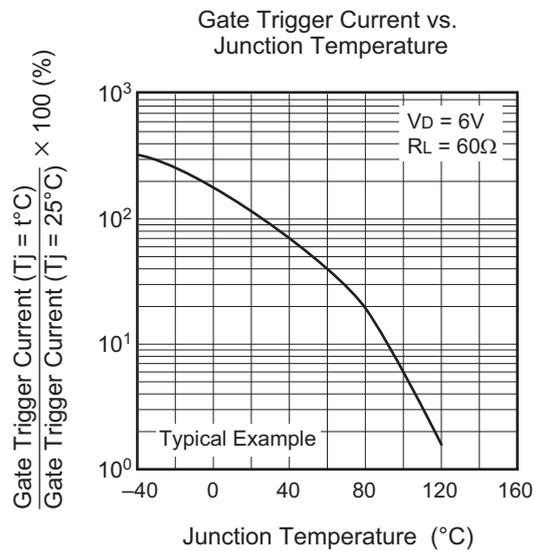
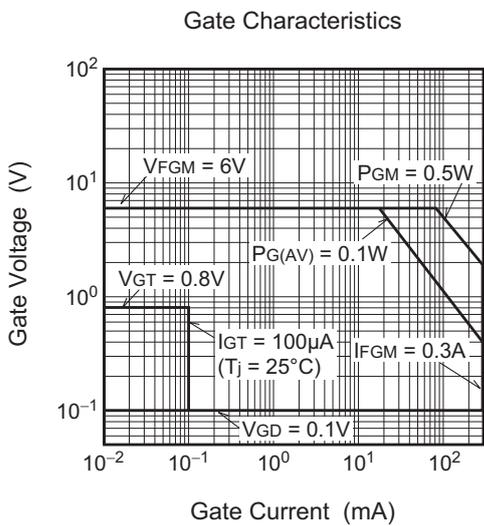
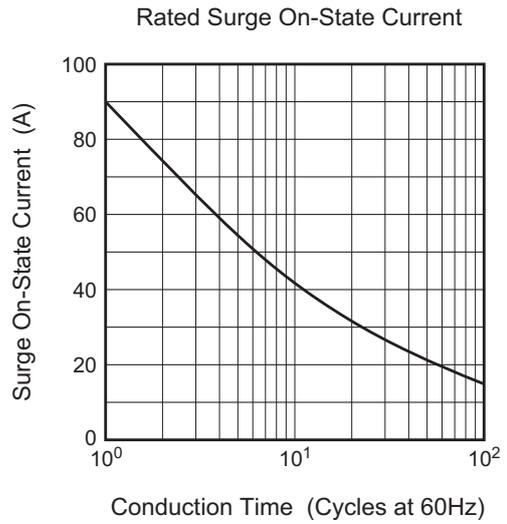
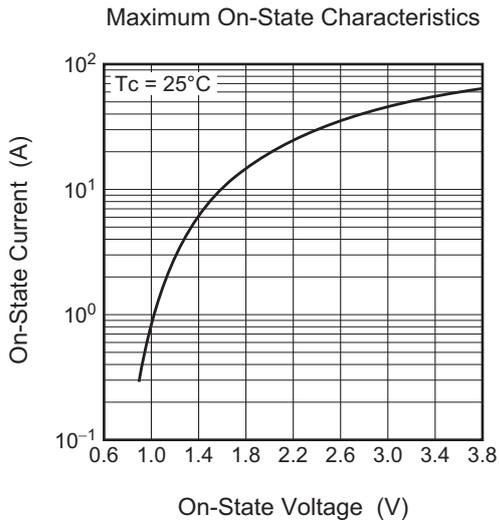
Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	7.8	A	
Average on-state current	$I_{T(AV)}$	5	A	Commercial frequency, sine half wave 180° conduction, $T_c = 88^\circ\text{C}$
Surge on-state current	$I_{TSM}$	90	A	60Hz sine half wave 1 full cycle, peak value, non-repetitive
$I^2t$ for fusing	$I^2t$	33	$\text{A}^2\text{s}$	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	0.5	W	
Average gate power dissipation	$P_{G(AV)}$	0.1	W	
Peak gate forward voltage	$V_{FGM}$	6	V	
Peak gate reverse voltage	$V_{RGM}$	6	V	
Peak gate forward current	$I_{FGM}$	0.3	A	
Junction temperature	$T_j$	- 40 to +125	$^\circ\text{C}$	
Storage temperature	$T_{stg}$	- 40 to +125	$^\circ\text{C}$	
Mass	—	0.32	g	MP-3A, Typical value
	—	0.36	g	DPAK(L)-(3), Typical value

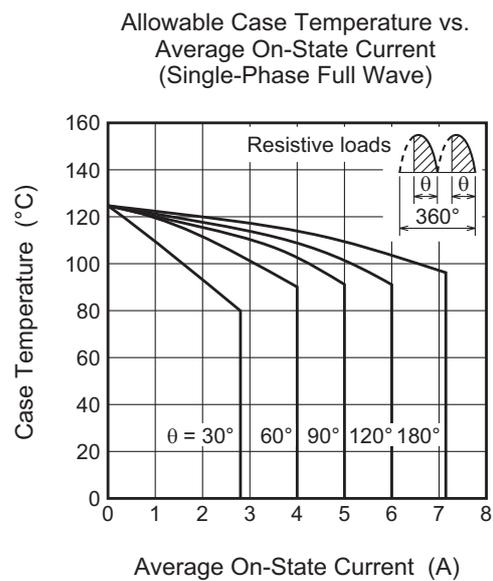
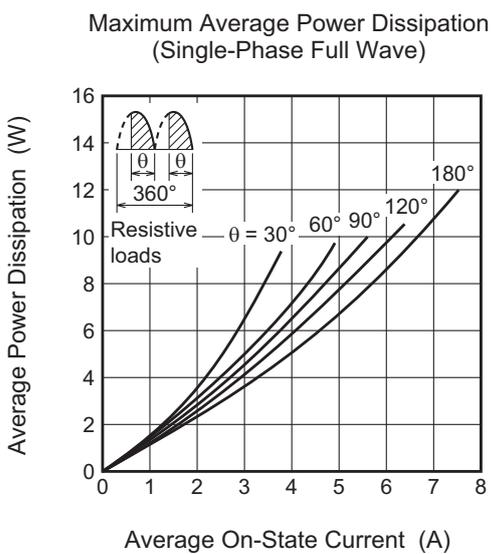
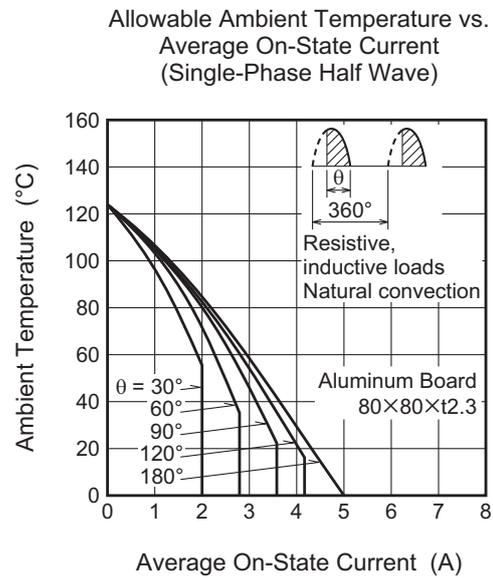
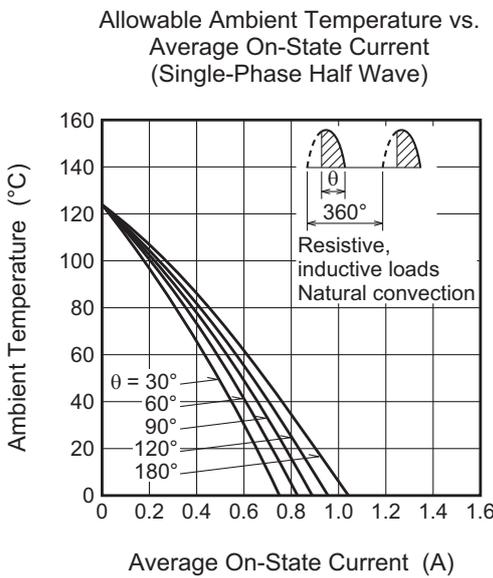
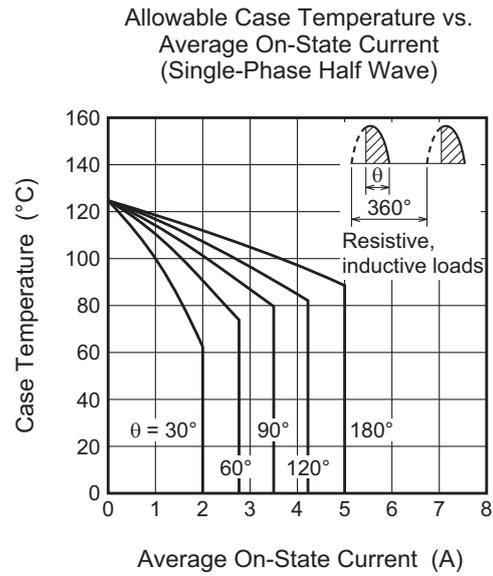
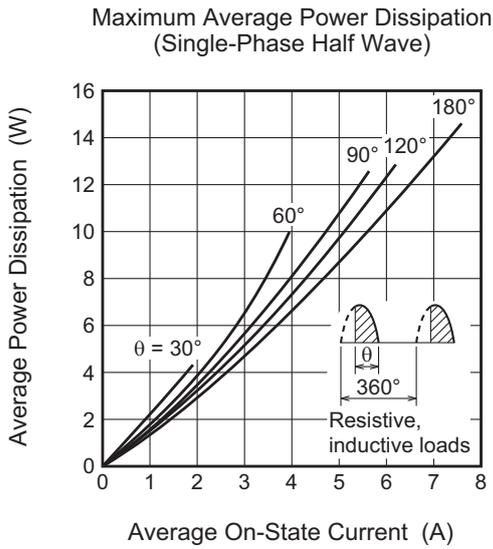
## Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak reverse current	$I_{RRM}$	—	—	1.0	mA	$T_j = 125^\circ\text{C}$ , $V_{RRM}$ applied, $R_{GK} = 220 \Omega$
Repetitive peak off-state current	$I_{DRM}$	—	—	1.0	mA	$T_j = 125^\circ\text{C}$ , $V_{DRM}$ applied, $R_{GK} = 220 \Omega$
On-state voltage	$V_{TM}$	—	—	1.8	V	$T_c = 25^\circ\text{C}$ , $I_{TM} = 15 \text{ A}$ , instantaneous value
Gate trigger voltage	$V_{GT}$	—	—	0.8	V	$T_j = 25^\circ\text{C}$ , $V_D = 6 \text{ V}$ , $I_T = 0.1 \text{ A}$
Gate non-trigger voltage	$V_{GD}$	0.1	—	—	V	$T_j = 125^\circ\text{C}$ , $V_D = 1/2 V_{DRM}$ , $R_{GK} = 220 \Omega$
Gate trigger current	$I_{GT}$	1	—	100	$\mu\text{A}$	$T_j = 25^\circ\text{C}$ , $V_D = 6 \text{ V}$ , $I_T = 0.1 \text{ A}$
Holding current	$I_H$	—	3.5	—	mA	$T_j = 25^\circ\text{C}$ , $V_D = 12 \text{ V}$ , $R_{GK} = 220 \Omega$
Thermal resistance	$R_{th(j-c)}$	—	—	3.0	$^\circ\text{C/W}$	Junction to case <sup>Note2</sup>

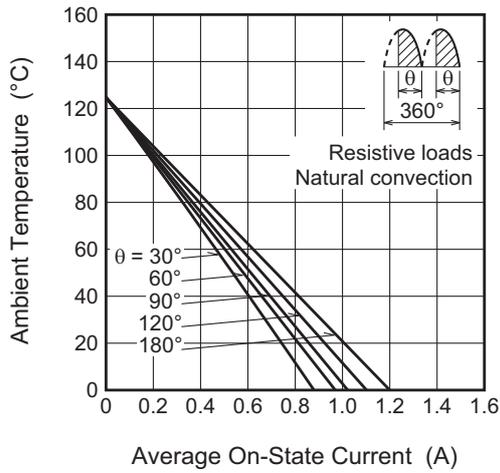
Notes: 2. The measurement point for case temperature is at anode tab.

Performance Curves

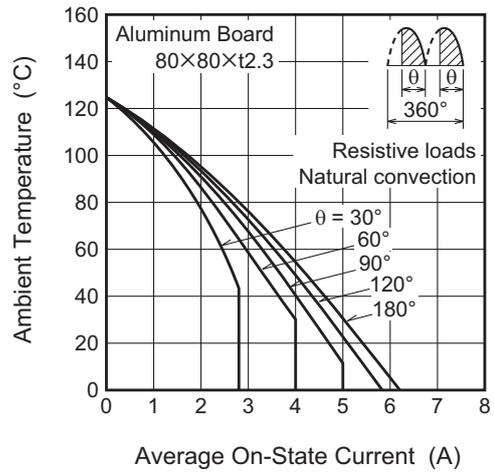




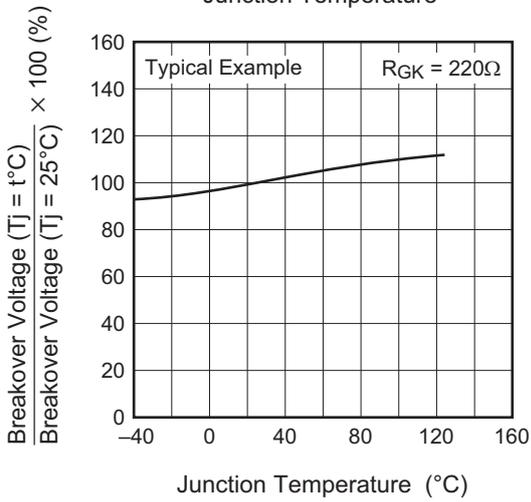
Allowable Ambient Temperature vs. Average On-State Current (Single-Phase Full Wave)



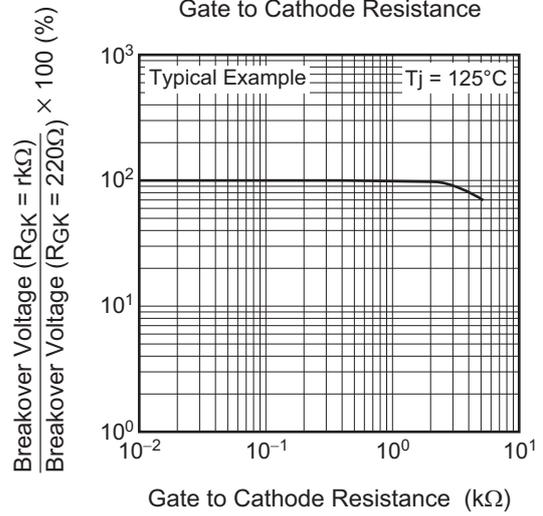
Allowable Ambient Temperature vs. Average On-State Current (Single-Phase Full Wave)



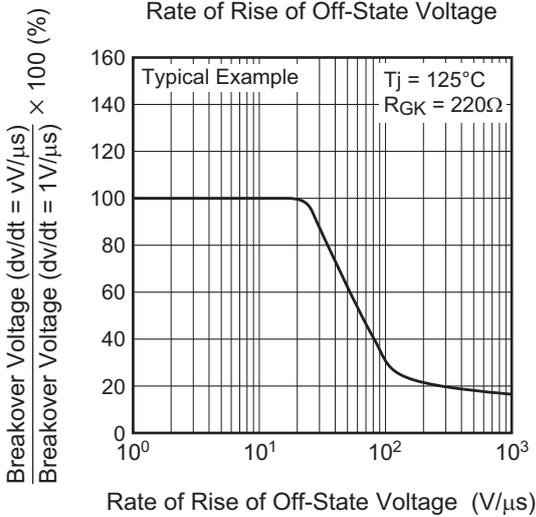
Breakover Voltage vs. Junction Temperature



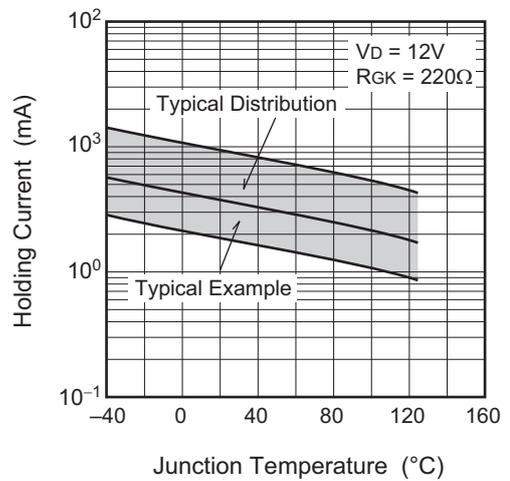
Breakover Voltage vs. Gate to Cathode Resistance



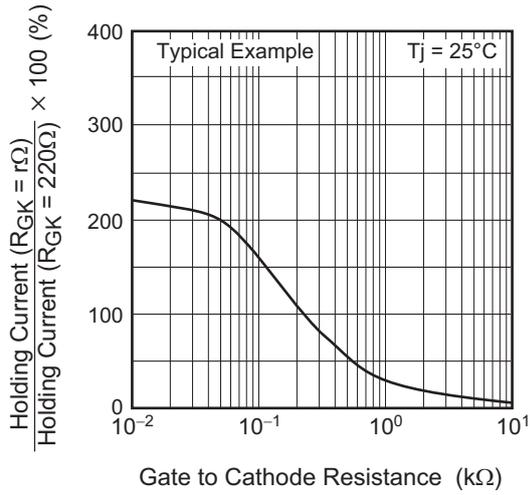
Breakover Voltage vs. Rate of Rise of Off-State Voltage



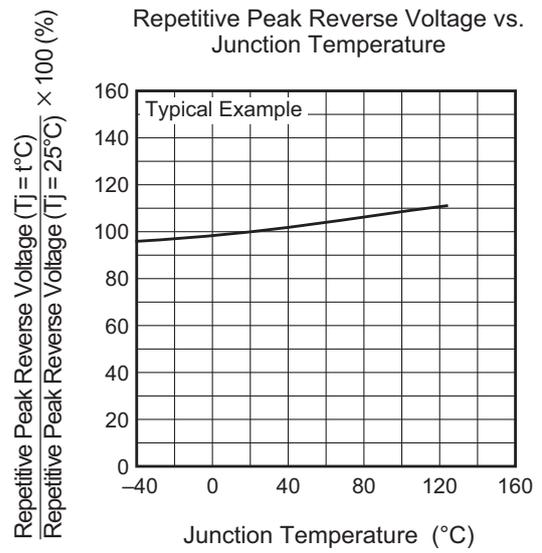
Holding Current vs. Junction Temperature



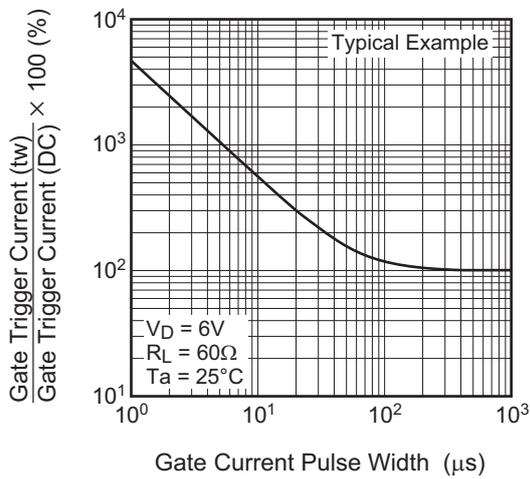
Holding Current vs. Gate to Cathode Resistance



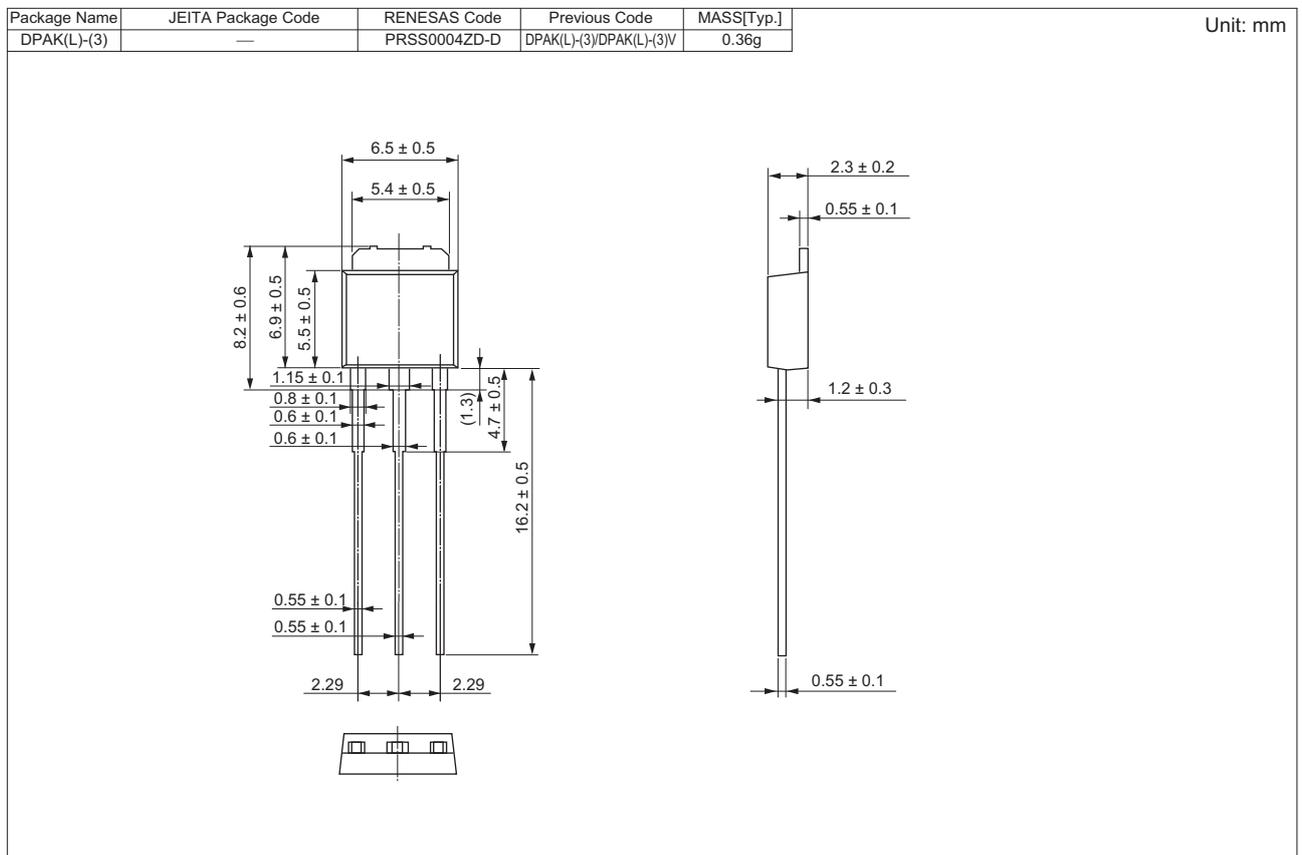
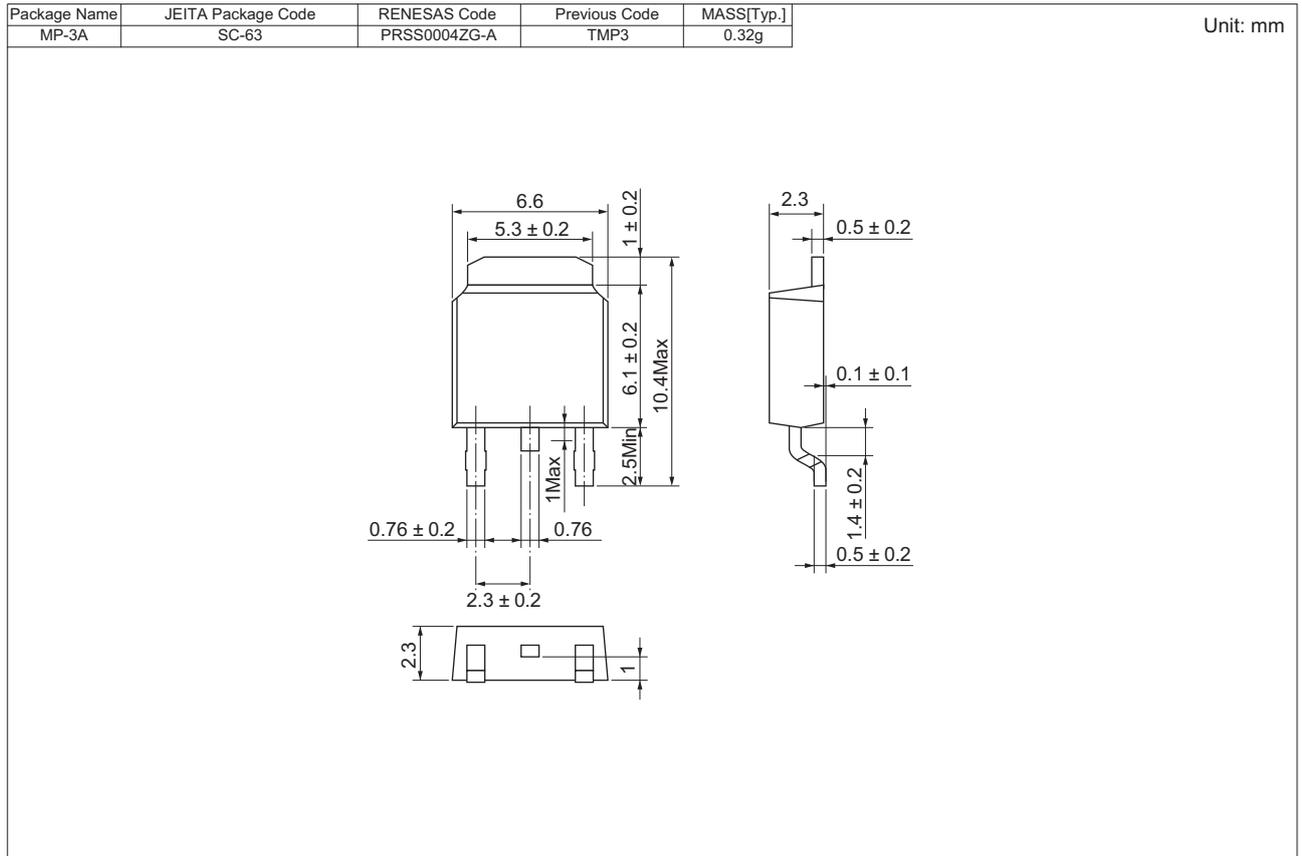
Repetitive Peak Reverse Voltage vs. Junction Temperature



Gate Trigger Current vs. Gate Current Pulse Width



### Package Dimensions



**Ordering Information**

Orderable Part Number	Packing	Quantity	Package	IGT
CR5AS-12A#B01	Tube	75 pcs.	MP-3A	1-100 $\mu$ A
CR5AS-12A#C04	Tube	75 pcs.	MP-3A	20-50 $\mu$ A
CR5AS-12A#C05	Tube	75 pcs.	MP-3A	20-100 $\mu$ A
CR5AS-12A-T13#B01	Embossed Tape	3000 pcs.	MP-3A	1-100 $\mu$ A
CR5AS-12A-T13#C04	Embossed Tape	3000 pcs.	MP-3A	20-50 $\mu$ A
CR5AS-12A-T13#C05	Embossed Tape	3000 pcs.	MP-3A	20-100 $\mu$ A
CR5AS-12A-A1#B00	Tube	80 pcs.	DPAK(L)-(3)	1-100 $\mu$ A
CR5AS-12A-BA1#B00	Tube	80 pcs.	DPAK(L)-(3)	20-50 $\mu$ A
CR5AS-12A-EA1#B00	Tube	80 pcs.	DPAK(L)-(3)	20-100 $\mu$ A

Note : Please confirm the specification about the shipping in detail.

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